Hydrogenated amorphous carbon (a-C:H) films can be deposited in a large variety of forms, exhibiting a diversity of physical and chemical properties. These properties are determined by the respective proportions of $sp^2$ and $sp^3$ carbon sites, controlling the microstructure of the film. The hydrogen incorporation in the film is one of the key quantities determining these $sp^2$ and $sp^3$ proportions. In order to better understand how H is incorporated into a growing film, and how this H incorporation influences the microstructure of the films, we present a series of simulations in which thin a-C:H films were deposited under identical conditions, varying only the H flux towards the substrate.

The model used in these simulations is based on the Brenner potential for hydrocarbons, and was originally developed by Tanaka et al. A clean diamond (111) surface is exposed to consecutive particle impacts. Each impact was followed for 2 ps, applying a heat bath set at 100 K during the last 0.4 ps. The output of every impact is the input for the next impact. After each impact, unbound atoms are removed from the configuration. Growth was continued until the films reached a thickness of about 10 nm, each containing about 4000 atoms. After the growth phase, the films were allowed to relax for 10 ps. A more detailed description of the model can be found elsewhere.

Conditions were chosen to simulate deposition systems in which chemical growth by radical species is the dominant growth mechanism. An example is the class of remote plasma sources when no substrate bias is applied. The relative particle fluxes in an expanding thermal plasma are determined by the respective proportions of deposited in a large variety of forms, exhibiting a diversity of chemical reactions at the surface, i.e., chemisorption. This process is dependent on the structure of the surface itself. Hence, a given radical can react differently on different surfaces, leading to different films. As the relative H flux towards the substrate increases, the H content in the film increases proportionally. There is an almost linear correspondence between the H flux and H incorporation in the film, as can be seen in Fig. 1 (see inset). Vice versa, the H flux towards the substrate can thus be estimated from the measured H content in the film. Also, the H distribution among the C atoms in the films is directly related to the H content, as can be seen in Fig. 1. Here, the calculated fractions of C, CH, and CH$_2$ groups in the films are shown as a function of the H content. The fraction of C atoms carrying both one and two H atoms increases as the H flux towards the substrate increases. The fraction of chain-terminating CH$_3$ groups was found to be negligible in all simulated films.

High hydrogen fluxes make the resulting structure more porous and less dense, as will be shown below. The decrease in mass density of a-C:H films with increasing H content has already been shown—see, e.g., the study by Ferrari et al. for films containing more than 40% $sp^3$ content, and references therein. In Fig. 2, it is shown that this effect also occurs under the conditions used in this study for high enough H fluxes. The figure shows the calculated mass density and atom density of the different films as a function of the H content in the bulk of the film. At low H fluxes, the mass density increases as a function of H flux (or H content), until a maximum is found at a H content of about 10%. The atom density, however, continues to increase as a function of the H content. Indeed, a high hydrogen flux allows the incorporation of a large H fraction into the carbon matrix, increasing the atom density. This, however, does not increase the mass density.
density due to the low hydrogen mass. A maximum in the atom density is found at a H content of about 22%, corresponding to a H flux of about 30%, according to Fig. 1. The occurrence of bulky CH2 groups at high H fluxes accounts for the decrease in both the mass density and atom density at a H content >25%. Also, as more H is incorporated into the film, relatively less C atoms must accommodate relatively more H atoms, increasing the average carbon coordination number, in the range of 2.8–3.1 for a H particle flux varying from 0% to 45%.

Hydrogen also changes considerably the microstructure of the films. In Fig. 3, the evolution of the $sp^1$, $sp^2$, and $sp^3$ C sites in the bulk of the film is plotted as a function of the H content. Here, a carbon site is designated $sp^1$ if the carbon atom is one or two coordinated. Likewise, $sp^2$ sites and $sp^3$ sites are identified as three-coordinated and four-coordinated C atoms, respectively. It can be seen in the figure that low H fluxes lead to a lowering of the $sp^1$ content, an increase in the $sp^2$ content, and a slight increase in the $sp^3$ content. This transition from $sp^1$ to $sp^2$ as a function of the H content in the film coincides with the maximum in the mass density. In this region, the film structure is composed of a network of $sp^2$-like C–C bonds, stabilized by chemical resonance. As the $sp^1$ sites occupy a larger volume per atom than $sp^2$ sites ($sp^1$ sites are linear one-dimensional structures while $sp^2$ sites are two dimensional), the $sp^1$ to $sp^2$ transition effectively lowers the volume per atom, and hence increases the mass density.

Higher H fluxes further lower the $sp^1$ content and strongly increase the $sp^3$ content, whereas the $sp^2$ content remains more or less constant. In this region, a considerable fraction of the film volume is taken by the H atoms, contributing only to the atom density, and hardly to the mass density. Hence, the films now become more porous and less dense.

At even higher H fluxes ($\Phi_{H,rel}>0.30$), the $sp^2$ carbon atoms are converted into $sp^3$ carbons, coinciding with the maximum found in the atom density. As can be seen in Fig. 1, the fraction of bulky CH2 groups now becomes important. These groups repel each other, such that from this point on, both the atom density and the mass density decrease. Hence, as the H flux towards the substrate increases, there is a H-induced $sp^1$ to $sp^2$ to $sp^3$ shift.

### Table I

<table>
<thead>
<tr>
<th>Species</th>
<th>Relative flux</th>
</tr>
</thead>
<tbody>
<tr>
<td>C</td>
<td>0.71(1–$\Phi_{H,rel}$)</td>
</tr>
<tr>
<td>CH</td>
<td>0.05(1–$\Phi_{H,rel}$)</td>
</tr>
<tr>
<td>C2</td>
<td>0.20(1–$\Phi_{H,rel}$)</td>
</tr>
<tr>
<td>C2H</td>
<td>0.04(1–$\Phi_{H,rel}$)</td>
</tr>
</tbody>
</table>

**FIG. 1.** Calculated hydrogen distribution among the C atoms as a function of the H content in the film; the calculated H content in the films as a function of the H flux is shown in the inset.

**FIG. 2.** Calculated mass densities and atom densities as a function of the H content in the films.

**FIG. 3.** Calculated $sp^1$, $sp^2$, and $sp^3$ C fractions as a function of the H content in the films.
The precision of our simulations is difficult to estimate, because the calculations are very time consuming, and it is not feasible to repeat them a few times every run. However, to check the precision of our simulations, two control runs were performed using H fluxes of 10% and 20%, respectively. The fractional H contents in the two films produced using the 10% H flux were 0.10 and 0.11, while the proportional differences in mass density, atom density, $sp^2$ fraction and average C-coordination number are 0.90%, 1.64%, 0.06%, and 0.10%. The H contents in the films produced using the 20% H flux were 0.16 and 0.18, while the proportional differences in mass density, atom density, $sp^2$ fraction, and average C-coordination number are 0.40%, 1.72%, 1.67%, and 0.25%. These control runs therefore demonstrate the typical precision expected for the simulations.

In conclusion, the H uptake in the film is quasilinearly dependent on the H flux. At low H fluxes, some hydrogen is incorporated into the film, leading to an increase in the atom density. This also leads to a conversion of $sp^1$ to $sp^2$ carbon sites, coinciding with an increase in the mass density. The maximum mass density of 1.79 g cm$^{-3}$ is found at a H content of about 10%. Higher H fluxes bring more H into the film, leading to a higher atom density, but a lower mass density, while $sp^1$ C sites are further converted to $sp^2$ sites, and $sp^2$ sites to $sp^3$ sites. Finally, at even higher H fluxes, the mass density keeps decreasing, and a maximum is found in the atom density, at a H flux of 30%. From this point on, the $sp^2$ content starts to decrease, coinciding with a decrease in the atom density and an increase in the fraction of CH$_2$ (see Fig. 1). Experimentally, a H content of about 33% and a mass density of about 1.5 g cm$^{-3}$ were found, corresponding very well with our simulations.

From these results, the H flux towards the substrate can be estimated by measuring the H content in the films. Also, these results show how a-C:H films, grown from low-kinetic energy radicals, can be densified using low H fluxes. These results are relevant for experimental deposition conditions where no ion bombardment is present, and show that even without ion bombardment densification is possible, by varying the H flux towards the substrate.

One of the authors (E.N.) is indebted to the Institute for the Promotion of Innovation by Science and Technology in Flanders (IWT-Flanders) for financial support. The authors would like to thank R. Gijbels and J. Benedikt for the many fruitful discussions.

---